<u>TOSHIBA</u>

TOSHIBA Photo-Interrupters Infrared LED + Phototransistor

TLP822(F),TLP827(F)

Lead Free Product

Vcrs, Compact Disc Players

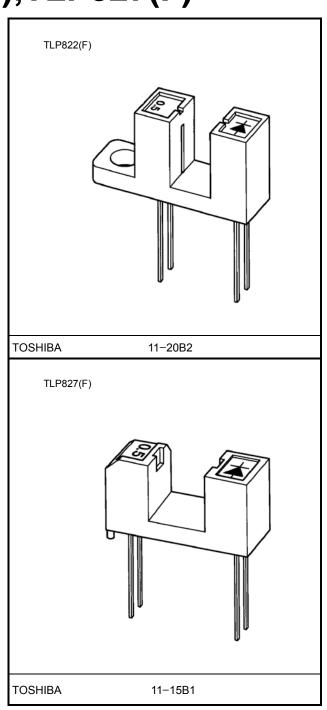
Floppy Disk Drives, Fax Machines, Printers

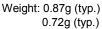
Vending Machines

Various Position Detection Sensors

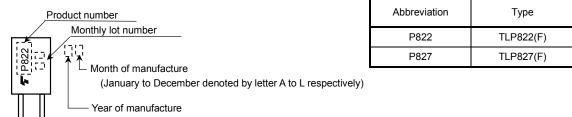
The TLP822(F) and TLP827(F) photo-interrupters combine a high-radiant-power GaAs infrared LED with an Si phototransistor.

- Small package
- Side mounting type: TLP822(F)
- Designed for direct mounting on printed circuit boards: TLP827(F) (the oblong slit)
- Gap: 5mm
- Resolution: Slit width = 0.5mm
- High current transfer ratio: IC / IF=5%(min) at IF=10mA
- Detector impermeable to visible light
- Package material: polycarbonate





Markings



(Last digit of year of manufacture)

Letter color: Silver

Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit	
LED	Forward current		١ _F	50	mA	
	Forward current derating	(Ta > 25°C)	ΔI _F / °C	-0.33	mA / °C	
		(Ta > 85°C)		-2(Note)	IIIA7 C	
	Reverse voltage		V _R	5	V	
	Collector-emitter voltage		V _{CEO}	35	V	
Detector	Emitter-collector voltage		V _{ECO}	5	V	
	Collector power dissipation		P _C	75	mW	
ă	Collector power dissipation derating		ΔP _C / °C	-1	mW / °C	
	Collector current		Ι _C	50	mA	
Ope	rating	TLP822(F)	т	-25~85	°C.	
temp	perature range	TLP827(F)	T _{opr}	-25~95	C	
Storage temperature range			T _{stg}	-40~100	°C	
Soldering temperature (5 s)			T _{sol}	260	°C	

(Note): TLP827(F) only

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{CC}	_	5	24	V
Forward current	١ _F	—	10	20	mA
Operating temperature	T _{opr}	-10	_	75	°C

Optical And Electrical Characteristics(Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	V _F	I _F = 10mA	1.00	1.15	1.30	V
	Reverse current	I _R	V _R = 5V	_	_	10	μA
	Peak emission wavelength	λ _P	I _F = 10mA	-	940	-	nm
Detector	Dark current	I _D (I _{CEO})	V _{CE} =24V,I _F =0	_	-	0.1	μA
	Peak sensitivity wavelength	λ _P	_	_	870	_	nm
	Current transfer ratio	I _C / I _F	V _{CE} =2V,I _F =10mA	5	-	75	%
Coupled	Collector-emitter saturation voltage	V _{CE(sat)}	I _F =20mA,I _C =0.5mA	_	0.1	0.4	V
	Rise time	tr	V _{CC} =5V,I _C =1mA,R _I =1kΩ	_	15	50	116
	Fall time	t _f	ייטטי-טיי,וט- ווויה,וען- ואנע	_	15	50	μs

Precautions

The following points must be borne in mind.

- 1. Clean only the soldered part of the leads. Do not immerse the entire package in the cleaning solvent.
- 2. The package is made of polycarbonate. Polycarbonate is usually stable with acid, alcohol and aliphatic hydrocarbons; however, with petrochemicals (such as benzene, toluene and acetone), alkalis, aromatic hydrocarbons, or chloric hydrocarbons, polycarbonate may crack, swell or melt. Please take this into account when choosing a packaging material by referring to the table below.

<Chemicals Which Should Not Be Used With Polycarbonate>

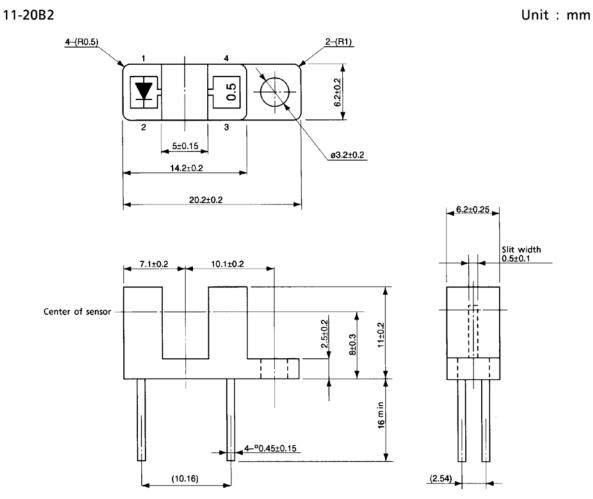
	Phenomenon	Chemicals
А	Staining and slight deterioration	Nitric acid (diluted), hydrogen peroxide, chlorine
в	Cracking, crazed or swelling	 Acetic acid (70% or more) Gasoline Methyl ethyl ketone, ethyl acetate, butyl acetate Ethyl methacrylate, ethyl ether, MEK Acetone, m–amino alcohol, carbon tetrachloride Carbon disulfide, trichloroethylene, cresol Thinners, oil of turpentine Triethanolamine, TCP, TBP
с	Melting (): Used as solvent	 Concentrated sulfuric acid Benzene Styrene, acrylonitrile, vinyl acetate Ethylenediamine, diethylenediamine (Chloroform, methyl chloride, tetrachloromethane, dioxane, 1, 2–dichloroethane)
D	Decomposition	 Ammonia water Other alkalis

3. Mount the device on a level surface.

- 4. Screws should be tightened to a clamping torque of 0.59 N·m.
- 5. Conversion efficiency falls over time due to the current which flows in the infrared LED. When designing a circuit, take into account this change in conversion efficiency over time. The ratio of fluctuation in conversion efficiency to fluctuation in infrared LED optical output is 1: 1.

 $\frac{I_{C} / I_{F} (t)}{I_{C} / I_{F} (0)} = \frac{P_{O} (t)}{P_{O} (0)}$

Package Dimensions



(): Reference value

Weight: 0.87 g (typ.)

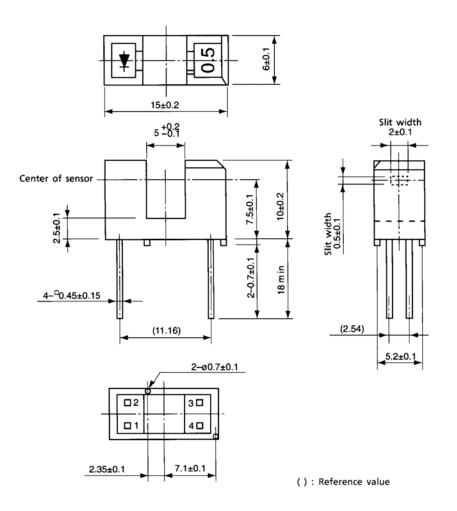
Pin Connection

- 1. Anode
- 2. Cathode
- 3. Collector
- 4. Emitter

Package Dimensions

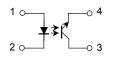
11-15B1

Unit : mm

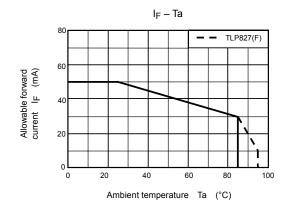


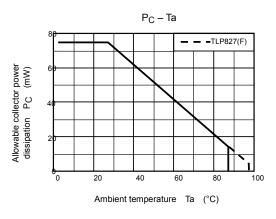
Weight: 0.72 g (typ.)

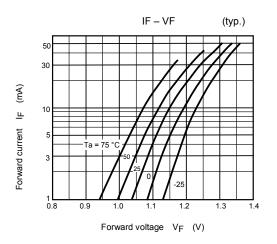
Pin Connection

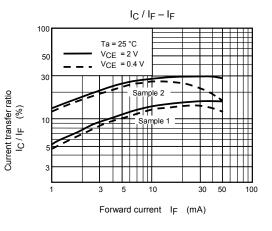


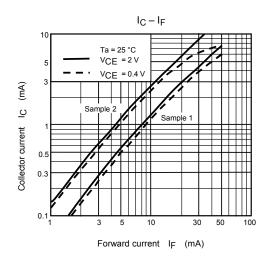
- 1. Anode
- 2. Cathode
- 3. Collector
- 4. Emitter

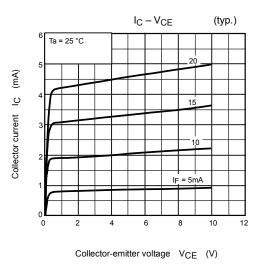


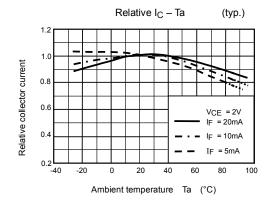


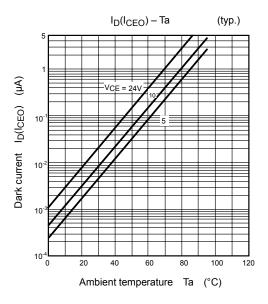


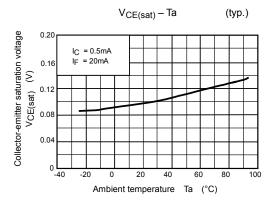




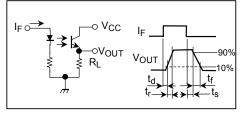


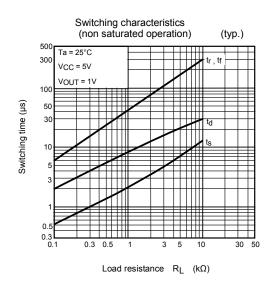


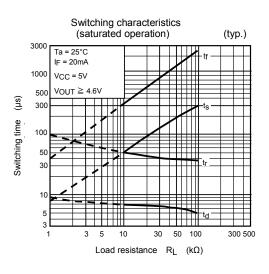


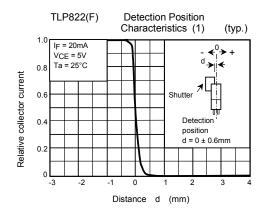


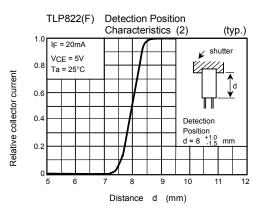


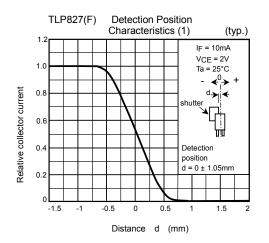


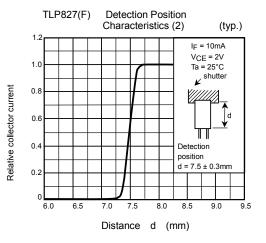








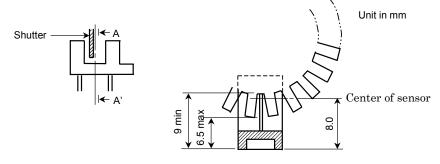




Relative Positioning Of Shutter And Device

For normal operation position the shutter and the device as shown in the figure below. By considering the device's detection position characteristic and switching time, determine the shutter slit width and pitch.

TLP822(F)



Cross section between A and A'

RESTRICTIONS ON PRODUCT USE

030619EAC

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor
 devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical
 stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of
 safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of
 such TOSHIBA products could cause loss of human life, bodily injury or damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.